

100V PNP MEDIUM POWER TRANSISTOR IN SOT223

Features

- $BV_{CEO} > -100V$
- $I_C = -5A$ high Continuous Collector Current
- $I_{CM} = -10A$ Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)} < -90mV @ -1A$
- $R_{SAT} = 60m\Omega$ for a low equivalent On-Resistance
- h_{FE} specified up to $-10A$ for a high gain hold up
- **Lead-Free Finish; RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP capable (Note 4)**

Mechanical Data

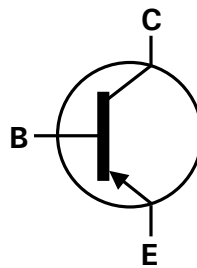
- Case: SOT223
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 **e3**
- Weight: 0.112 grams (approximate)

Applications

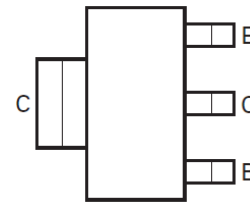
- Motor driving
- Line switching
- High side switches
- Subscriber line interface cards (SLIC)



Top View



Device Symbol



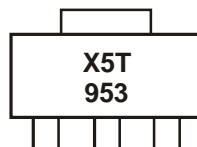
Top View
Pin-Out

Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZX5T953GTA	AEC-Q101	X5T953	7	12	1,000
ZX5T953GQTA	Automotive	X5T953	7	12	1,000

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
 5. For packaging details, go to our website at <http://www.diodes.com>

Marking Information



X5T953 = Product type Marking Code

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-140	V
Collector-Emitter Voltage	V _{CEO}	-100	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	I _C	-5	A
Peak Pulse Current	I _{CM}	-10	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

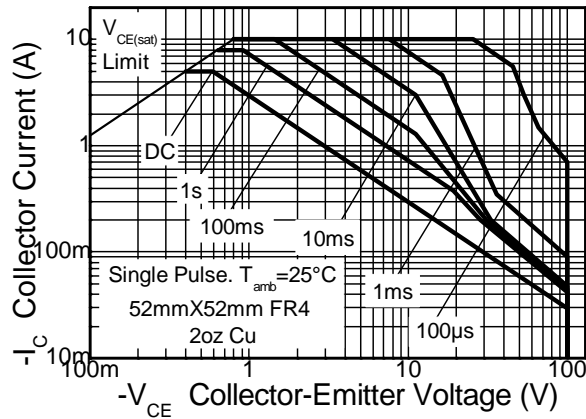
Characteristic	Symbol	Value	Unit
Power Dissipation Linear derating factor	P _D	3.0	W
		24	
		1.6	
		12.8	
Thermal Resistance, Junction to Ambient	R _{θJA}	42	°C/W
	R _{θJA}	78	
Thermal Resistance Junction to Lead	R _{θJL}	10.48	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 9)

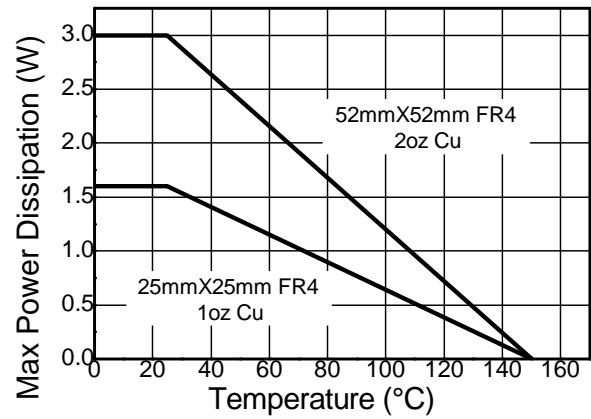
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	C

- Notes:
6. For a device surface mounted on 52mm x 52mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 7. Same as note (6), except the device is surface mounted on 25mm x 25mm with 1oz copper.
 8. Thermal resistance from junction to solder-point (at the end of the collector lead).
 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

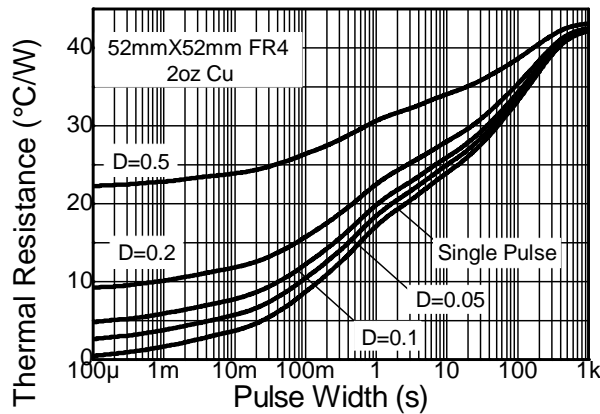
Thermal Characteristics and Derating Information



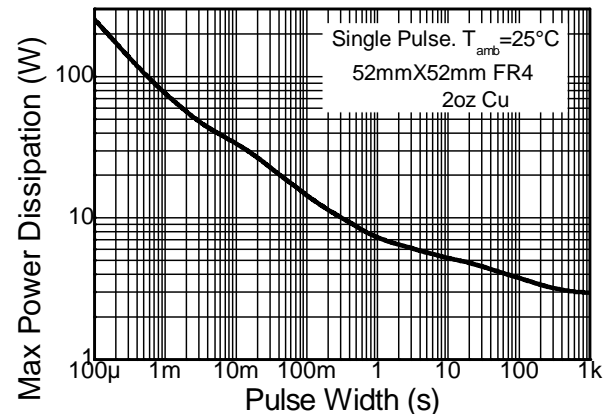
Safe Operating Area



Derating Curve



Transient Thermal Impedance



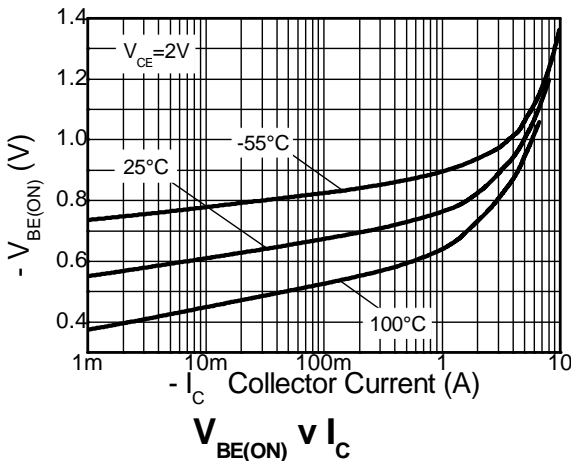
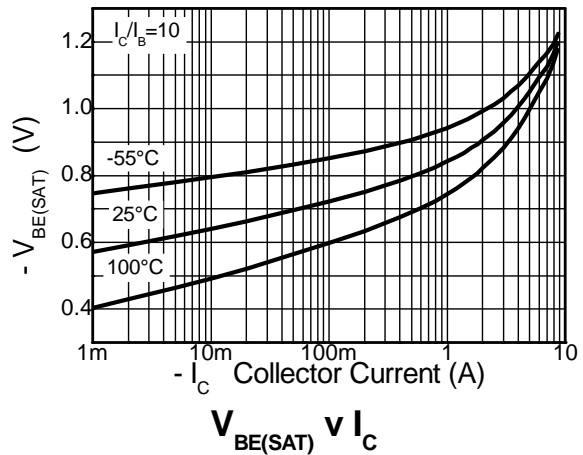
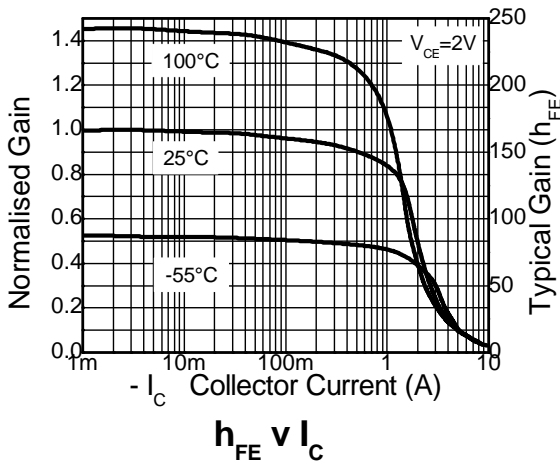
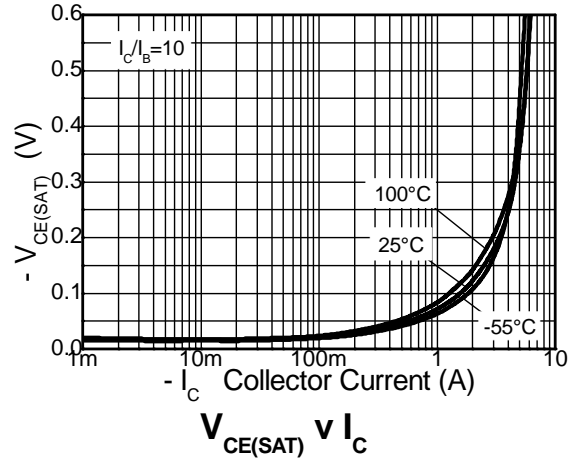
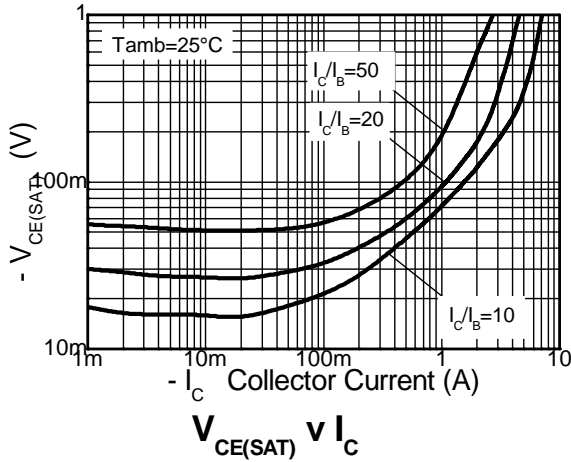
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-140	-160	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage	BV _{CER}	-140	-160	-	V	I _C = -1μA, R _B ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-100	-115	-	V	I _C = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.1	-	V	I _E = -100μA
Collector-Base Cutoff Current	I _{CBO}	-	<1	-20	nA	V _{CB} = -100V
				-0.5	μA	V _{CB} = -100V, T _A = +100°C
Collector-Emitter Cutoff Current	I _{CER} R ≤ 1kΩ	-	<1	-20	nA	V _{CB} = -100V
				-0.5	μA	V _{CB} = -100V, T _A = +100°C
Emitter Cutoff Current	I _{EBO}	-	<1	-10	nA	V _{EB} = -6V
Static Forward Current Transfer Ratio (Note 10)	h _{FE}	100	250	-	-	I _C = -10mA, V _{CE} = -1V
		100	200	300		I _C = -1A, V _{CE} = -1V
		25	50	-		I _C = -3A, V _{CE} = -1V
		15	30	-		I _C = -4A, V _{CE} = -1V
		-	5	-		I _C = -10A, V _{CE} = -1V
Collector-Emitter Saturation Voltage (Note 10)	V _{CE(sat)}	-	-20	-30	mV	I _C = -100mA, I _B = -10mA
		-	-70	-90		I _C = -1A, I _B = -100mA
		-	-120	-150		I _C = -2A, I _B = -200mA
		-	-240	-340		I _C = -4A, I _B = -400mA
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	-	-985	-1100	mV	I _C = -4A, I _B = -400mA
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	-	-920	-1050	mV	I _C = -4A, V _{CE} = -2V
Output Capacitance (Note 10)	C _{obo}	-	42	-	pF	V _{CB} = -10V, f = 1MHz
Transition Frequency	f _T	-	125	-	MHz	V _{CE} = -10V, I _C = -100mA f = 50MHz
Switching Time	t _{on}	-	42	-	ns	V _{CC} = -10V, I _C = -1A I _{B1} = I _{B2} = -100mA
	t _{off}	-	540	-		

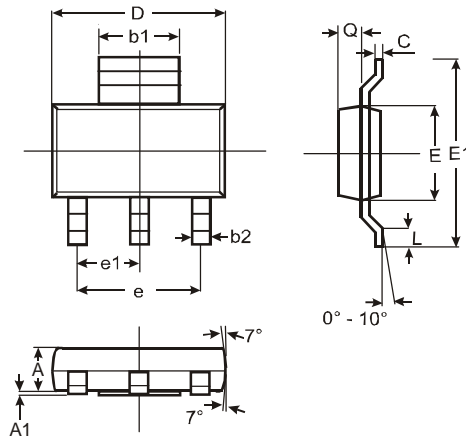
Notes: 10. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Package Outline Dimensions

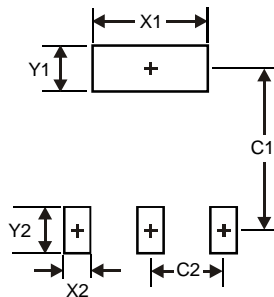
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b1	2.90	3.10	3.00
b2	0.60	0.80	0.70
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	—	—	4.60
e1	—	—	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

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